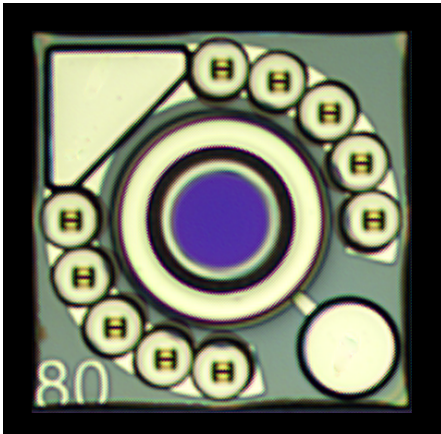


# OG-AP-080-12 APD

## Product Brief

*Our Photodiodes, Your Circuits*



### Features:

- High damage threshold
- Fast Recovery
- Wide dynamic range
- Low noise
- Low capacitance
- High reliability
- Also available in back-entry version

### Applications:

- Laser range finding
- Remote Sensing
- Machine vision
- Defense and Security
- Free-space optical communication

### Overview:

Our APDs offer a wide dynamic range with high damage threshold and fast recovery from high power optical pulses. These APDs are perfect for laser range finding applications that require high tolerance to large optical returns, while still able to detect low power signal levels. They are also suitable for free-space optical communication systems. These APDs come in various aperture sizes ranging from 30 microns to 350 microns. The back-entry version for lower capacitance and lensed version for enhanced sensitivity are available per request.

Operating Characteristics: Temperature = 25°C

Parameter	Min	Typ	Max	Units
Wavelength Range	1000	-	1630	nm
Responsivity @ M = 1	0.85	0.90	1.0	A/W
Dark Current @ M=10	-	1	15	nA
Operating Voltage, Vr @ M=10		55	70	volts
Breakdown Voltage (Id = 10 $\mu$ A)	40	65	80	volts
Aperture Diameter	78	80	82	$\mu$ m
Capacitance @ M=10	0.32	0.35	0.4	pF
Temperature coeff. of Vbr	0.05	0.06	0.07	V/°C
Bandwidth @ M = 10	2.0	2.5	3.0	GHz
Bandwidth @ M = 20	1.5	2.2	2.5	GHz
Excess Noise Factor, F @ M=10	-	3.2	3.7	
Excess Noise Factor, F @ M=20	-	5.5	6.0	
Noise Equivalent Power, NEP @ M=10	-	0.01	0.04	fW/ $\sqrt$ Hz

### Absolute Maximum Conditions

Parameter	Min	Max	Units
Operating Temp Range	-40	85	°C
Storage Temp Range	-55	125	°C
Max Reverse Current	-	1	mA
Max Forward Current	0	10	mA
Optical Input (10 nsec pulse)		>200	kW/cm <sup>2</sup>
Optical Input (average)	-	0	dBm

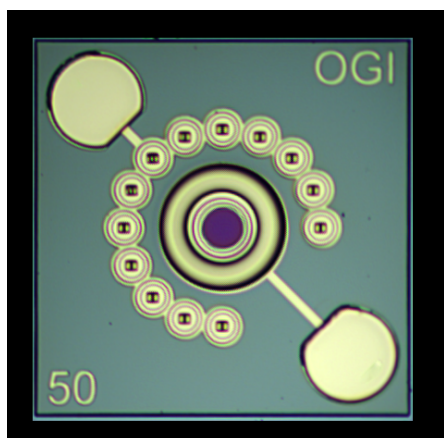
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# OG-AP-050-12 APD

## Product Brief

*Our Photodiodes, Your Circuits*



### Features:

- High damage threshold
- Fast Recovery
- Wide dynamic range
- Low noise
- Low capacitance
- High reliability
- Also available in back-entry version

### Applications:

- Laser range finding
- Remote Sensing
- Machine vision
- Defense and Security
- Free-space optical communication

### Overview:

Our APDs offer a wide dynamic range with high damage threshold and fast recovery from high power optical pulses. These APDs are perfect for laser range finding applications that require high tolerance to large optical returns, while still able to detect low power signal levels. They are also suitable for free-space optical communication systems. These APDs come in various aperture sizes ranging from 30 microns to 350 microns. The back-entry version for lower capacitance and lensed version for enhanced sensitivity are available per request.

Operating Characteristics: Temperature = 25°C

Parameter	Min	Typ	Max	Units
Wavelength Range	1000	-	1630	nm
Responsivity @ M = 1	0.85	0.90	1.0	A/W
Dark Current @ M=10	-	1	10	nA
Operating voltage, Vr @ M=10		55	70	volts
Breakdown Voltage (Id = 10 µA)	40	65	80	volts
Aperture Diameter	48	50	52	µm
Capacitance @ M=10	0.22	0.25	0.3	pF
Temperature coeff. of Vbr	0.05	0.06	0.07	V/°C
Bandwidth @ M = 10	2.5	3	3.5	GHz
Bandwidth @ M = 20	1.5	2.5	3	GHz
Excess Noise Factor, F @ M=10	-	3.2	3.7	
Excess Noise Factor, F @ M=20	-	5.5	6.0	
Noise Equivalent Power, NEP @ M=10	-	-	0.03	fW/√Hz

### Absolute Maximum Conditions

Parameter	Min	Max	Units
Operating Temp Range	-40	85	°C
Storage Temp Range	-55	125	°C
Max Reverse Current	-	1	mA
Max Forward Current	0	10	mA
Optical Input (10 nsec pulse)		>200	kW/cm <sup>2</sup>
Optical Input (average)	-	0	dBm

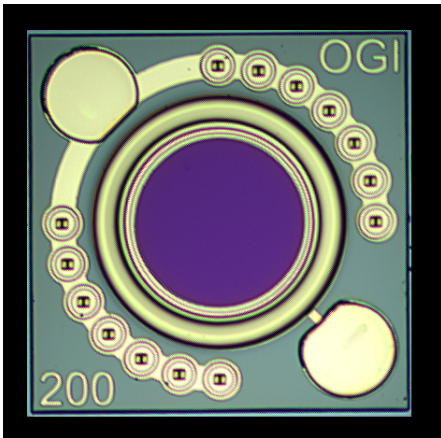
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# OG-AP-200-12 APD

## Product Brief

*Our Photodiodes, Your Circuits*



### Features:

- High damage threshold
- Fast Recovery
- Wide dynamic range
- Low noise
- Low capacitance
- High reliability
- Also available in back-entry version

### Applications:

- Laser range finding
- Remote Sensing
- Machine vision
- Defense and Security
- Free-space optical communication

### Overview:

Our APDs offer a wide dynamic range with high damage threshold and fast recovery from high power optical pulses. These APDs are perfect for laser range finding applications that require high tolerance to large optical returns, while still able to detect low power signal levels. They are also suitable for free-space optical communication systems. These APDs come in various aperture sizes ranging from 30 microns to 350 microns. The back-entry version for lower capacitance and lensed version for enhanced sensitivity are available per request.

Operating Characteristics: Temperature = 25°C

Parameter	Min	Typ	Max	Units
Wavelength Range	1000	-	1630	nm
Responsivity @ M = 1 1550nm wavelength	0.85	0.90	0.95	A/W
Dark Current @ M=10	-	8	25	nA
Operating voltage, Vr @ M=10	43	55	75	volts
Breakdown Voltage, Vbr (Id = 10 $\mu$ A)	50	63	83	volts
Aperture Diameter	200	205	210	$\mu$ m
Capacitance		1.5	2.0	pF
Temperature coeff. of Vbr		0.075		V/°C
Bandwidth @ M = 5	0.5	1.5	2.0	GHz
Bandwidth @ M = 10	1	1.5	2.0	GHz
Bandwidth @ M = 20	0.5	1.0	1.5	GHz
Excess Noise Factor, F @ M=10	-	3.2	3.7	-
Excess Noise Factor, F @ M=20	-	5.5	6.0	-
Noise Equivalent Power, NEP @ M=10	-	0.032	0.1	fW/ $\sqrt$ Hz

### Absolute Maximum Conditions

Parameter	Min	Max	Units
Operating Temp Range	-40	85	°C
Storage Temp Range	-55	125	°C
Max Reverse Current	-	1	mA
Max Forward Current	0	10	mA
Optical Input (10 nsec pulse)		>200	kW/cm <sup>2</sup>
Optical Input (average)	-	0	dBm

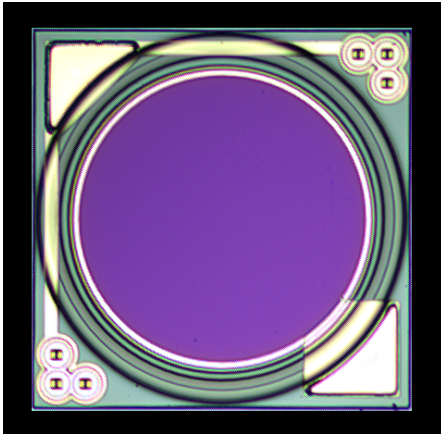
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# OG-AP-350-12 APD

## Product Brief

*Our Photodiodes, Your Circuits*



### Features:

- High damage threshold
- Fast Recovery
- Wide dynamic range
- Low noise
- Low capacitance
- High reliability
- Also available in back-entry version

### Applications:

- Laser range finding
- Remote Sensing
- Machine vision
- Defense and Security
- Free-space optical communication

### Overview:

Our APDs offer a wide dynamic range with high damage threshold and fast recovery from high power optical pulses. These APDs are perfect for laser range finding applications that require high tolerance to large optical returns, while still able to detect low power signal levels. They are also suitable for free-space optical communication systems. These APDs come in various aperture sizes ranging from 30 microns to 350 microns. The back-entry version for lower capacitance and lensed version for enhanced sensitivity are available per request.

Operating Characteristics: Temperature = 25°C

Parameter	Min	Typ	Max	Units
Wavelength Range	1000	-	1630	nm
Responsivity @ M = 1	0.85	0.90	0.95	A/W
Dark Current @ M=10	-	30	250	nA
Operating voltage, Vr @ M=10	37	52	68	volts
Breakdown Voltage (Id = 10 $\mu$ A)	45	60	75	volts
Aperture Diameter	350	352	355	$\mu$ m
Capacitance @ M=10	-	3.2	4.0	pF
Temperature coeff. of Vbr	0.05	0.06	0.07	V/°C
Bandwidth @ M = 10	-	0.6	-	GHz
Bandwidth @ M = 20	-	0.6	-	GHz
Excess Noise Factor, F @ M=10	-	3.2	3.7	-
Excess Noise Factor, F @ M=20	-	5.5	6.0	-
Noise Equivalent Power, NEP @ M=10	-	0.08	-	fW/ $\sqrt$ Hz

### Absolute Maximum Conditions

Parameter	Min	Max	Units
Operating Temp Range	0	70	°C
Storage Temp Range	-40	85	°C
Max Reverse Current	-	1	mA
Max Forward Current	0	10	mA
Optical Input	-	0	dBm

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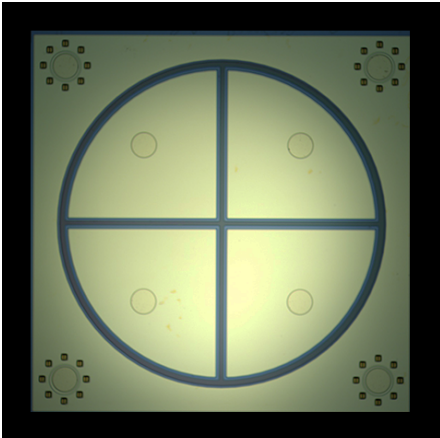
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# OG-QP-1000-60 BE-pin

## Product Brief

*Our Photodiodes, Your Circuits*



### Features:

- Low dark current
- Low capacitance
- High quantum efficiency

### Applications:

- Position sensing
- Laser spot tracking
- Defense and Security

### Overview:

Our PIN quad pixel arrays have low defect density, low capacitance, and low dark current that provides an ideal solution for reliable position sensing applications. These arrays come in 1 mm and 7 mm diameter versions.

Operating Characteristics: Temperature = 25°C

Parameter	Min	Typ	Max	Units
Wavelength Range	1000	-	1630	nm
Responsivity @ M = 1	0.85	0.95	-	A/W
Dark Current @ M=10	-	2		nA
Operating voltage, Vr @ M=10		0	11	volts
Breakdown Voltage (Id = 10 $\mu$ A)	15	20	65	volts
Capacitance @ M=10		50		pF
Capacitance @ M=10		10		$\mu$ m

# 128x128 InAlAs-InGaAs APD Array

## Product Brief

*Our Photodiodes, Your Circuits*

### Features:

- High uniformity across the FPA
- Wide operating gain range
- Large dynamic range
- High damage threshold
- Fast Recovery
- Low noise
- Low capacitance
- Built-in lens option available

### Applications:

- Precision vehicle maneuvering
- Machine vision
- Defense and Security

### Overview:

Our 2D APD arrays offer a wide dynamic range with high damage threshold and pixel gain uniformity across the array. These arrays are critical for precision vehicle maneuvering in space and defense applications. OGi designs these APDs in close collaboration with customer's requirements e.g. pixel pitch and can incorporate built-in lens on pixels for enhanced sensitivity.

Operating Characteristics: Temperature = 25°C

Parameter	Min	Typ	Max	Units
Wavelength Range	1000	-	1630	nm
Responsivity @ M = 1 1550nm wavelength (1550nm optimized AR coating)	0.80	0.85	0.90	A/W
Dark Current @ M=10	-	2	20	nA
Operating voltage, Vr @ M=10	46	55	73	volts
Breakdown Voltage, Vbr (Id = 10 μA)	55	63	82	volts
Active Diameter (without lens, @90% maximum)	48	50	60	μm
Capacitance		0.08	0.1	pF
Temperature coeff. of Vbr		0.07		V/°C
A-factor, M = A / (Vbr-Vop)	70	85	100	volts
Bandwidth @ M = 10	1.5	2.5	3	GHz
Bandwidth @ M = 20	1	1.5	2	GHz
Excess Noise Factor, F @ M=10	-	3.2	3.7	-
Excess Noise Factor, F @ M=20	-	5.5	6.0	-
Noise Equivalent Power, NEP @ M=10	-	0.01	0.05	fW/√Hz

Array Uniformity (within a single array with 100 μm pitch)

Parameter	Variation	Units
V10 non-uniformity	+/-0.5	V
A-factor non-uniformity	+/-2	%
Id20 non-uniformity	+/-5	nA
k <sub>eff</sub> non-uniformity	+/-5	%
Responsivity non-uniformity at V for M=10	+/-7	%

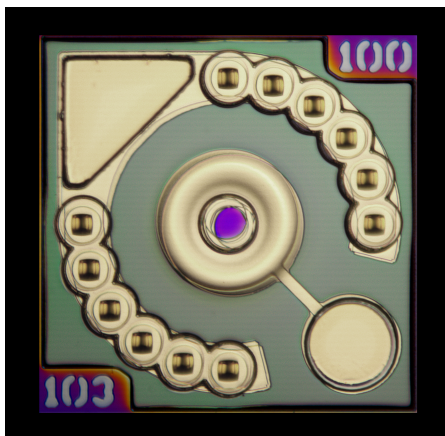
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# OG-AP-030-12 APD

## Product Brief

*Our Photodiodes, Your Circuits*



### Features:

- High damage threshold
- Fast Recovery
- Wide dynamic range
- Low noise
- Low capacitance
- High reliability
- Also available in back-entry version

### Applications:

- Laser range finding
- Remote Sensing
- Machine vision
- Defense and Security
- Free-space optical communication

### Overview:

Our APDs offer a wide dynamic range with high damage threshold and fast recovery from high power optical pulses. These APDs are perfect for laser range finding applications that require high tolerance to large optical returns, while still able to detect low power signal levels. They are also suitable for free-space optical communication systems. These APDs come in various aperture sizes ranging from 30 microns to 350 microns. The back-entry version for lower capacitance and lensed version for enhanced sensitivity are available per request.

Operating Characteristics: Temperature = 25°C

Parameter	Min	Typ	Max	Units
Wavelength Range	1000	-	1630	nm
Responsivity @ M = 1	-	0.90	-	A/W
Dark Current @ M=10	-	0.2	10	nA
Operating Voltage, Vr @ M=10	32	52	72	volts
Breakdown Voltage (Id = 10 $\mu$ A)	40	60	80	volts
Aperture Diameter	-	30	-	$\mu$ m
Capacitance @ M=10	-	0.14	-	pF
Temperature coeff. of Vbr	0.05	0.06	0.08	V/°C
Bandwidth @ M = 10	-	6	-	GHz
Bandwidth @ M = 20	-	4.5	-	GHz
Excess Noise Factor, F @ M=10	-	3.2	3.7	
Excess Noise Factor, F @ M=20	-	5.5	6.0	
Noise Equivalent Power, NEP @ M=10	-	-	-	fW/ $\sqrt$ Hz

### Absolute Maximum Conditions

Parameter	Min	Max	Units
Operating Temp Range	-40	85	°C
Storage Temp Range	-55	125	°C
Max Reverse Current	-	1	mA
Max Forward Current	0	10	mA
Optical Input (10 nsec pulse)		>200	kW/cm <sup>2</sup>
Optical Input (average)	-	0	dBm

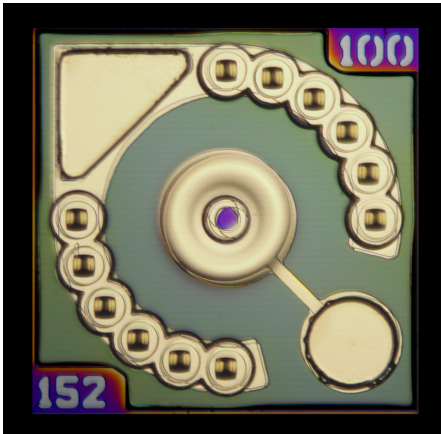
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# OG-AP-020-12 APD

## Product Brief

*Our Photodiodes, Your Circuits*



### Features:

- High damage threshold
- Fast Recovery
- Wide dynamic range
- Low noise
- Low capacitance
- High reliability
- Also available in back-entry version

### Applications:

- Laser range finding
- Remote Sensing
- Machine vision
- Defense and Security
- Free-space optical communication

### Overview:

Our APDs offer a wide dynamic range with high damage threshold and fast recovery from high power optical pulses. These APDs are perfect for laser range finding applications that require high tolerance to large optical returns, while still able to detect low power signal levels. They are also suitable for free-space optical communication systems. These APDs come in various aperture sizes ranging from 30 microns to 350 microns. The back-entry version for lower capacitance and lensed version for enhanced sensitivity are available per request.

Operating Characteristics: Temperature = 25°C

Parameter	Min	Typ	Max	Units
Wavelength Range	1000	-	1630	nm
Responsivity @ M = 1 1550 nm	-	0.90	-	A/W
Dark Current @ M=10	-	0.15	10	nA
Operating Voltage, Vr @ M=10	32	52	72	volts
Breakdown Voltage (Id = 10 $\mu$ A)	40	60	80	volts
Aperture Diameter	-	20	-	$\mu$ m
Capacitance @ M=10	-	0.09	-	pF
Temperature coeff. of Vbr	0.05	0.06	0.08	V/°C
Bandwidth @ M = 10	-	6	-	GHz
Bandwidth @ M = 20	-	4.5	-	GHz
Excess Noise Factor, F @ M=10	-	3.2	3.7	
Excess Noise Factor, F @ M=20	-	5.5	6.0	
Noise Equivalent Power, NEP @ M=10	-	-	-	fW/ $\sqrt$ Hz

### Absolute Maximum Conditions

Parameter	Min	Max	Units
Operating Temp Range	-40	85	°C
Storage Temp Range	-55	125	°C
Max Reverse Current	-	1	mA
Max Forward Current	0	10	mA
Optical Input (10 nsec pulse)		>200	kW/cm <sup>2</sup>
Optical Input (average)	-	0	dBm

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